1 key Touch Pad Detector IC

Outline

- The TTP223E-CA6 TonTouch™ is a touch pad detector IC which offers 1 touch key. Stable sensing method can cover diversity conditions. The touching detection IC is designed for replacing traditional direct button key with diverse pad size. Low power consumption and wide operating voltage are the contact key features for DC or AC application.

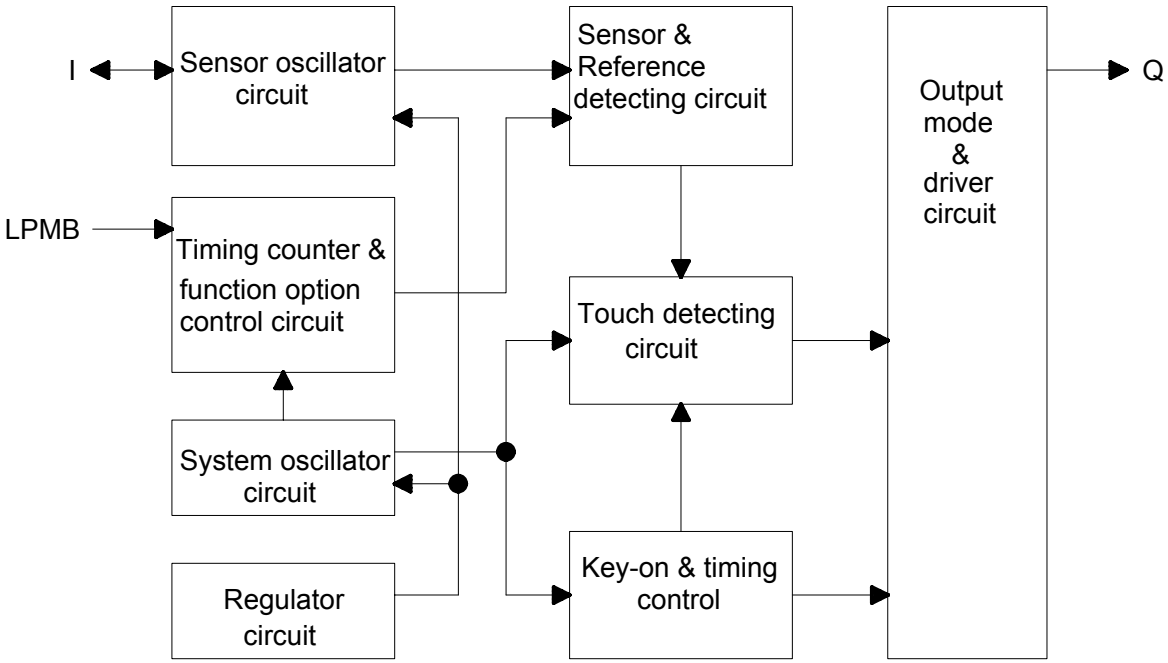
Characteristic

- Operating voltage 2.0V ~ 5.5V
- Operating current, @VDD=3V no load
  At low power mode typical 2.0uA, maximum 4.0uA
  At fast mode typical 5.0uA, maximum 10.0uA
- The response time max about 60mS at fast mode, 220mS at low power mode @VDD=3V
- Sensitivity can adjust by the capacitance（1~50pF）outside
- Stable touching detection of human body for replacing traditional direct switch key
- Provides Fast mode and Low Power mode selection by pad option (LPMB pin)
- Q pin is CMOS output and active high
- After power-on have about 0.5sec stable-time, during the time do not touch the key pad, and the function is disabled
- Auto calibration for life
  The re-calibration period is about 1 sec within 8 sec after power-on. When key has been touched within 8 sec or key has not been touched more than 8 sec after power-on, then the re-calibration period change to 4 sec

Applications

- Wide consumer products
- Button key replacement

Block diagram



Pin Description

Pin NO	Pin Name	Type	Pin Description
1	Q	O	CMOS output pin
2	VSS	P	Negative power supply, ground
3	I	I/O	Input sensor port
4	VSS	P	Negative power supply, ground
5	VDD	P	Positive power supply
6	LPMB	I-PH	Low power mode selection, 1(Default)=>Fast mode; 0=>Low power mode

Pin Type

- I CMOS input only
- O CMOS push-pull output
- I／O CMOS I／O
- P Power／Ground
- I-PH CMOS input and pull-high resister
- I-PL CMOS input and pull-low resister
- OD Open drain output, have no Diode protective circuit

Electrical Characteristics

- **Absolute maximum ratings**

Parameter	Symbol	Conditions	Rating	Unit
Operating Temperature	T_{OP}	—	-40～+85	℃
Storage Temperature	T_{STG}	—	-50～+125	℃
Supply Voltage	VDD	Ta=25°C	VSS-0.3～VSS+5.5	V
Input Voltage	V_{IN}	Ta=25°C	VSS-0.3～VDD+0.3	V
Human Body Mode	ESD	—	5	KV
Note：VSS symbolizes for system ground				

- **DC / AC characteristics：（Test condition at room temperature = 25 ℃）**

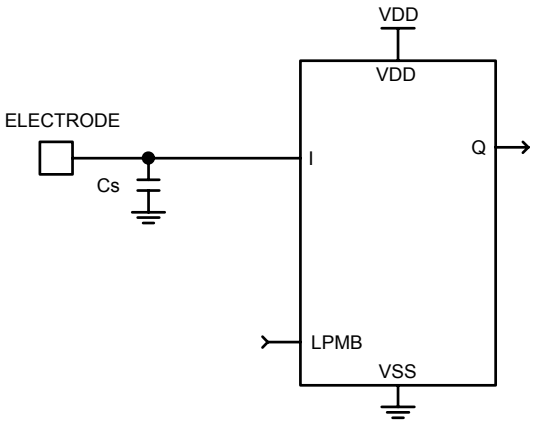
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Operating Voltage	VDD		2.0	3	5.5	V
Operating Current	I_{OPL}	VDD=3V, At low power mode		2.0	4.0	uA
	I_{OPF}	VDD=3V, At fast mode		5.0	10.0	uA
Input Ports	V_{IL}	Input Low Voltage	0		0.2	VDD
Input Ports	V_{IH}	Input High Voltage	0.8		1.0	VDD
Output Port Sink Current	I_{OL}	VDD=3V, V_{OL}=0.6V		8		mA
Output Port Source Current	I_{OH}	VDD=3V, V_{OH}=2.4V		-4		mA
Input Pin Pull-low Resistor	R_{PL}	VDD=3V (TOG, AHLB)		25K		ohm
Output Response Time	T_R	VDD=3V、 At fast mode			60	mS
		VDD=3V、 At low power mode			220	

Function Description

Ⅰ. Sensitivity adjustment

The total loading of electrode size and capacitance of connecting line on PCB can affect the sensitivity. So the sensitivity adjustment must according to the practical application on PCB. The TTP223E-CA6 offers some methods for adjusting the sensitivity outside.

1. by the electrode size
   Under other conditions are fixed. Using a larger electrode size can increase sensitivity. Otherwise it can decrease sensitivity. But the electrode size must use in the effective scope.
2. by the panel thickness
   Under other conditions are fixed. Using a thinner panel can increase sensitivity. Otherwise it can decrease sensitivity. But the panel thickness must be below the maximum value.
3. by the value of Cs（please see the down figure）
   Under other conditions are fixed. When do not use the Cs to VSS, the sensitivity is most sensitive. When adding the value of Cs will reduce sensitivity in the useful range （1≦Cs≦50pF）.



Ⅱ. Output mode

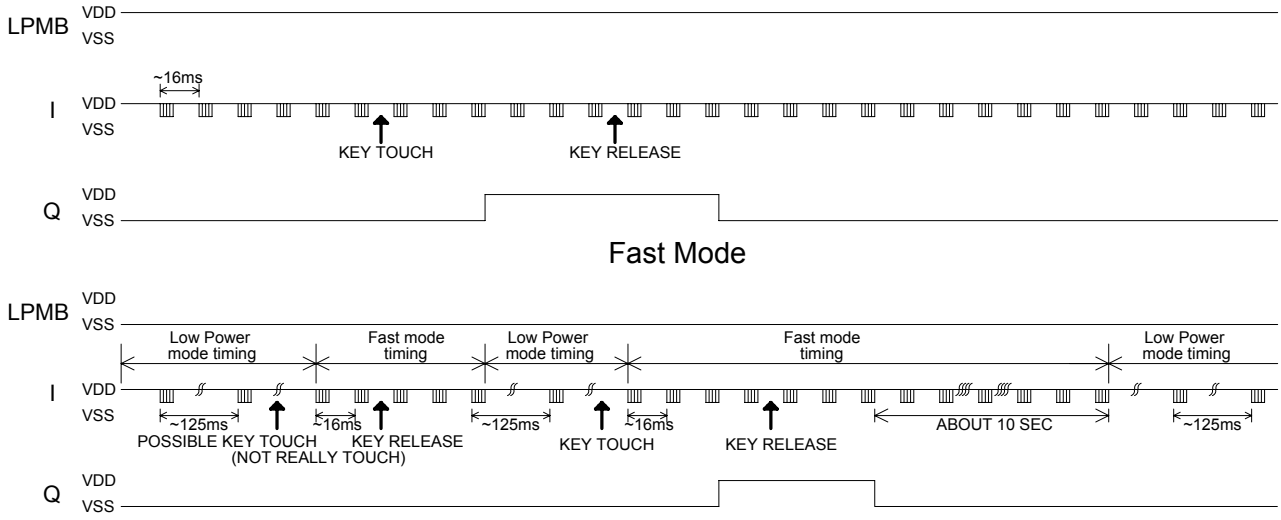
The Q pin of TTP223E-CA6 is direct mode CMOS output active high

Ⅲ. Fast and Low power mode selection（By LPMB pad option）

The TTP223E-CA6 has Fast mode and Low Power mode to be selected. It depends on the state of LPMB pad. When the LPMB pin is opened or connected to VDD, the TTP223E-CA6 runs in Fast mode. When the LPMB pin is connected to VSS, the TTP223E-CA6 runs in Low Power mode.

In the Fast mode response time is faster, but the current consumption will be increased. In the Low Power mode it will be saving power, but will be slowing response time for first touch. When it awaked in fast mode, the response time is the same the fast mode. In this mode when detecting key touch, it will switch to Fast mode. Until the key touch is released and will keep a time about 10 sec. Then it returns to Low Power mode.

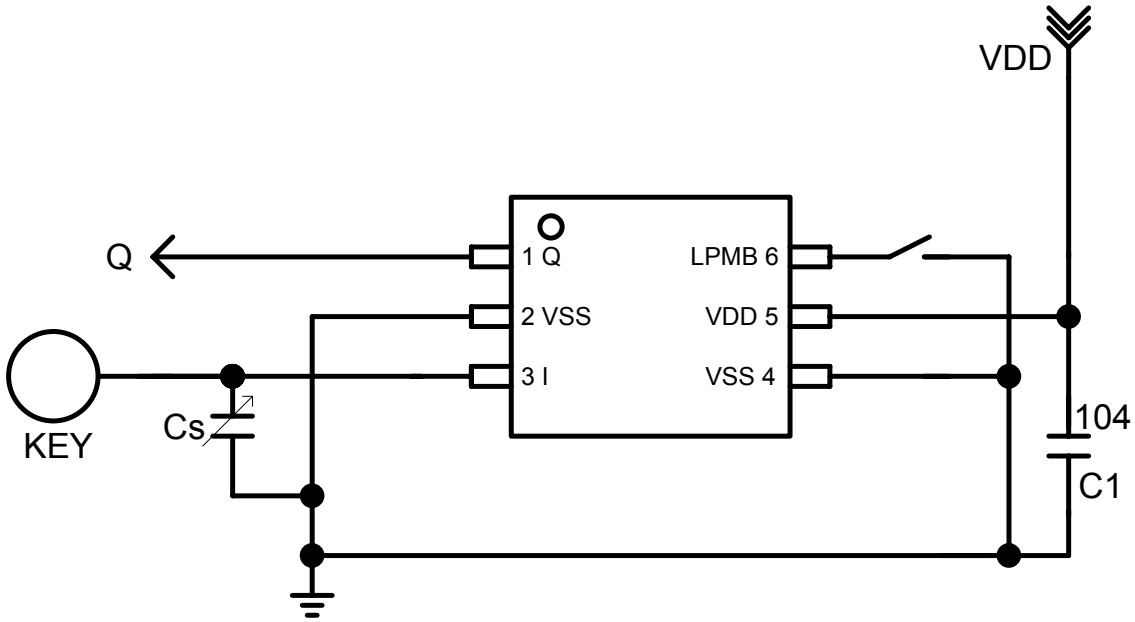
The states and timing of two modes please see below figure.



Low Power Mode

LPMB	Option features
1	Fast mode
0	Low Power mode

Application circuit

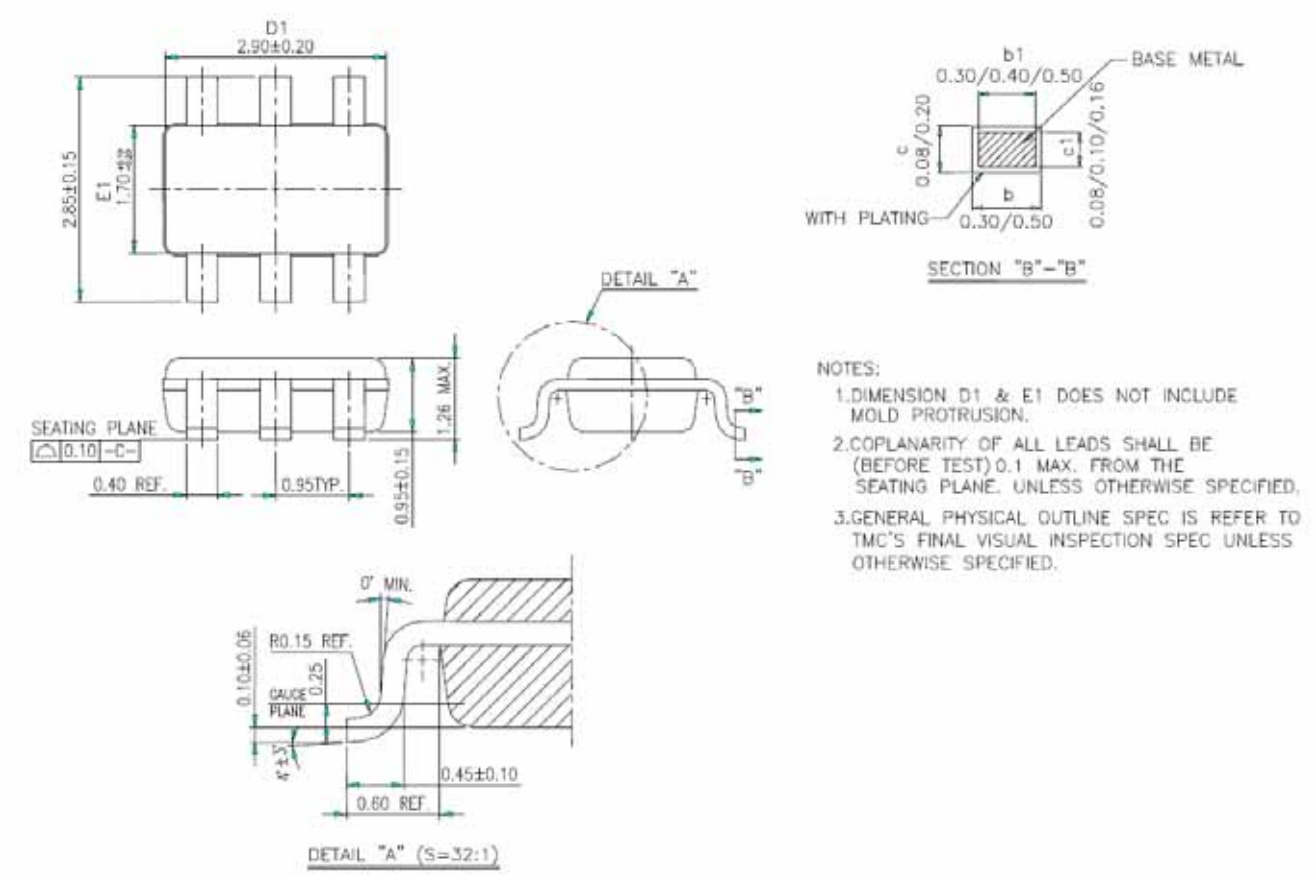


P.S.：

1. On PCB, the length of lines from touch pad to IC pin shorter is better.
   And the lines do not parallel and cross with other lines.
2. The power supply must be stable. If the supply voltage drift or shift quickly, maybe causing sensitivity anomalies or false detections.
3. The material of panel covering on the PCB can not include the metal or the electric element. The paints on the surfaces are the same.
4. The C1 capacitor must be used between VDD and VSS; and should be routed with very short tracks to the device's VDD and VSS pins (TTP223E-CA6).
5. The capacitance Cs can be used to adjust the sensitivity. The value of Cs use smaller, then the sensitivity will be better. The sensitivity adjustment must according to the practical application on PCB. The range of Cs value are 1~50pF.
6. The sensitivity adjustment capacitors（Cs）must use smaller temperature coefficient and more stable capacitors. Such are X7R, NPO for example. So for touch application, recommend to use NPO capacitor, for reducing that the temperature varies to affect sensitivity.

Package outline

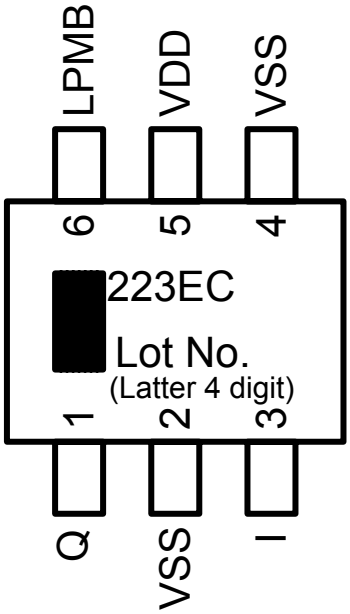
Package Type: SOT23-6L



Package configuration

TTP223E-CA6

Package Type SOT23-6L



Ordering Information

TTP223E-CA6		
Package Type	**Chip Type**	**Wafer Type**
TTP223E-CA6	No support	No support

REVISE HISTORY

1. 2016/04/28
   - Original version：V1.0